

科目：工程數學 C(5005)

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一. (5%)

(一) (2%) Solve $y' = y^2, y(0) = 2$. Call the solution y_c .

(二) (2%) Solve $y' = y^2 - 1, y(0) = 1$. Call the solution y_p .

(三) (1%) Does $y_c + y_p$ solve $y' = y^2 - 1, y(0) = 3$? Explain.

二. (8%) One solution of the equation $y'' + p(t)y' + q(t)y = 0$ is $(1+t)^2$, and the Wronskian of any two solutions is constant. Find the general solution of $y'' + p(t)y' + q(t)y = 1+t$.

三. (5%) Three solutions of a 2nd-order linear equation $L(y) = g(t)$ are

$$\psi_1 = 2e^{t^2} + e^t, \psi_2 = te^{t^2} + e^t \text{ and } \psi_3 = (1+t)e^{t^2} + e^t.$$

Find the solution of the initial problem $L(y) = g(t); y(0) = 3, y'(0) = 0$.

四. (8%) Let y be a real function of x . Find two linearly independent Frobenius solutions of the following differential equation at $x = 0$:

$$2x^2 y'' + x(x-3)y' + 3y = 0$$

五. (8%) Let x_1 and x_2 be two real functions of t . Solve x_1 and x_2 for the following system of differential equations

$$\begin{cases} x_1' = 4x_1 - x_2 \\ x_2' = x_1 + 2x_2 \end{cases}, x_1(1) = 5, x_2(1) = 3$$

六. (7%) Given the initial value problem, $x'' + 4x' + 13x = f(t); x(0) = x'(0) = 0$

(一) (3%) Express $x(t)$ in terms of $f(t)$ and convolution.

(二) (4%) Solve $x(t)$ for $f(t) = u(t) - u(t-1)$, where $u(t)$ denotes the unit step (or Heaviside Step) function.

七. (9%) $f(t) = \begin{cases} 1, & 0 < t < 5 \\ 0, & 5 < t < 10 \end{cases}$ with $f(t+10) = f(t)$ is a piecewise continuous and periodic function that satisfies $f(t) = \frac{f(t^+) + f(t^-)}{2}$, where $f(t^+)$ and $f(t^-)$ are the right-hand and left-hand limits of $f(t)$ at each discontinuity.

(一) (3%) Find the Fourier series of $f(t)$.

(二) (3%) Let $f(t)$ be defined for $t \geq 0$; find its Laplace transform $F(s)$ for $s > 0$.

(三) (3%) Find a particular solution for $x'' + 16x = f(t)$.

八. (9%) Consider the following partial differential equation: $\frac{\partial^2 u}{\partial t^2} = 4 \frac{\partial^2 u}{\partial x^2}$

For the moment let's assume that u is in the form of $u = A \sin \lambda x \cos \omega t$, where A , λ , and ω are non-zero constants.

(一) (3%) What is the relationship between λ and ω ?

(二) (3%) Assuming that u must satisfy the condition $u(x=0, t) = u(x=8, t) = 0$, what is λ ? Notice that λ might not be single valued.

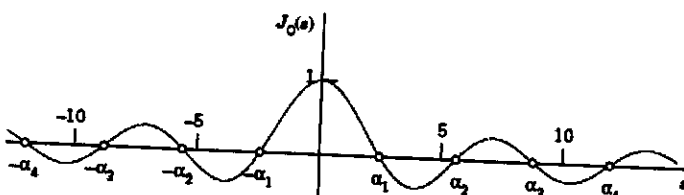
(三) (3%) What is the lowest possible frequency of u ?

九. (4%) Given the equation for the circular membrane vibration: $\frac{\partial^2 u}{\partial t^2} = c^2 \left(\frac{\partial^2 u}{\partial r^2} + \frac{1}{r} \frac{\partial u}{\partial r} \right)$

with the boundary condition: $u(r=20, t) = 0$ and c is a constant, the solution is in the form of

$$u = \sum_{n=1}^{\infty} u_n = \sum_{n=1}^{\infty} W_n T_n = \sum_{n=1}^{\infty} (A_n \cos ck_n t + B_n \sin ck_n t) J_0(k_n r)$$

where J_0 is the Bessel function of the first kind. Find the nodal line (curves on the membrane that do not move) for $n = 2$. Note that J_0 has infinitely many positive zeros $\alpha_1, \alpha_2, \alpha_3, \dots$ as shown in the following figure.



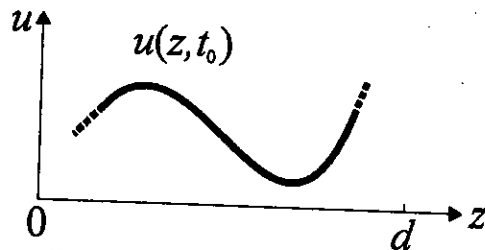
注意：背面有試題

+. (12%) Consider a bulk of silicon with dimension $l \times w \times d$, where the thickness d (along the z -axis) is much smaller than the length l and width w . The diffusion and annealing of dopant ions is governed by the diffusion equation:

$$\frac{\partial u}{\partial t} = \alpha^2 \frac{\partial^2 u}{\partial z^2}, \quad (t > 0, 0 < z < d)$$

where $u(z, t)$ means the dopant ion density and α^2 represents the diffusivity.

(-) (6%) Let the dopant ion density profile somewhere inside the silicon at a certain instant t_0 , i.e. $u(z, t_0)$, look like as shown in the figure. Without detailed calculation, please roughly draw the new dopant ion density profile corresponding to a very short time Δt later, i.e. $u(z, t_0 + \Delta t)$.



(-) (3%) Write down the boundary conditions if all the dopant ions cannot escape from the bulk of silicon.

(≡) (3%) Without detailed calculation, can you draw the steady-state dopant ion density profile $u(z, t \rightarrow \infty)$ by using $u(z, t_0)$ as shown and the boundary conditions specified in part (-)?

+-. (13%) For a 3x3 matrix A , where

$$A = \begin{bmatrix} 3 & -1 & -2 \\ 2 & 0 & -2 \\ 2 & -1 & -1 \end{bmatrix}$$

(-) (6%) Please find its eigenvalues and corresponding eigenvectors.

(-) (7%) Assume the 3 eigenvalues are in the order of $\lambda_1 \leq \lambda_2 \leq \lambda_3$. Starting from the eigenvector corresponding to λ_1 , please find the corresponding orthonormal basis.

+-. (12%) Define the space P_n as the set of all polynomials of degree less than n . Let L be the operator on P_3 and

$$L(p(x)) = \alpha + x \frac{d}{dx} p(x) + \frac{d^2}{dx^2} p(x)$$

(-) (3%) Find the matrix A representing L with respect to $[1, x, x^2]$.

(-) (3%) Find the matrix B representing L with respect to $[1, x, 1+x^2]$.

(≡) (3%) Find the condition of α such that A and B are similar matrices.

(四) (3%) If $p(x) = a_0 + a_1x + a_2x^2$, calculate $L^n(p(x))$ given the condition of α in (≡).